



N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
20	0.0035 at $V_{GS} = 4.5 \text{ V}$	25			
	0.0047 at V _{GS} = 2.5 V	20			

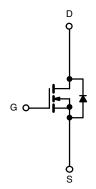
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFETs: 2.5 V Rated
- Low 3.5 m Ω R_{DS(on)}
- PWM (Q_{gd} and R_g) Optimized



APPLICATIONS

• Low-Side MOSFET in Synchronous Buck DC/DC Converters in Servers and Routers



N-Channel MOSFET

			SO-8		
S	1			8	D
S	2			7	D
S	3			6	D
G	4			5	D
		_	Top View	ı	

Ordering Information: Si4864DY-T1-E3 (Lead (Pb)-free) Si4864DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS Parameter	,,	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20			
Gate-Source Voltage		V _{GS}	± 8		V	
0 11 0 1/7 17000	T _A = 25 °C	- I _D	25	17		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		20	13		
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	60		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3		
Maniana Banas Birata atian	T _A = 25 °C	D	3.5	1.6	W	
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	2.2	1	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mariana Indiana Indiana	t ≤ 10 s	R _{thJA}	29	35		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	67	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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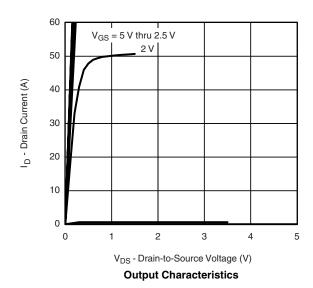
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	ymbol Test Conditions		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		2	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA		
Zava Cata Valtaga Dvain Cuvvant	l	V _{DS} = 20 V, V _{GS} = 0 V		1				
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α		
D : 0	В	$V_{GS} = 4.5 \text{ V}, I_D = 25 \text{ A}$	= 25 A		0.0035	Ω		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 20 \text{ A}$ 0.0038		0.0038	0.0047			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 6 V, I _D = 25 A		70		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.70	1.1	V		
Dynamic ^b								
Total Gate Charge	Qg			47	70			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 25 \text{ A}$		10		nC		
Gate-Drain Charge	Q_{gd}			13.4				
Gate Resistance	R_g		0.5	1.5	2.6	Ω		
Turn-On Delay Time	t _{d(on)}			40	60			
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		44	65			
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 4.5 V, R_g = 6 Ω		150	240	ns		
Fall Time	t _f			72	110			
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.9 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		57	80			

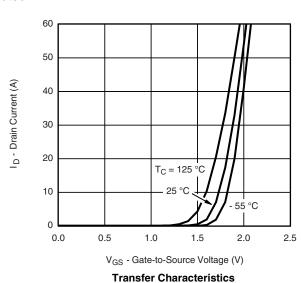
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

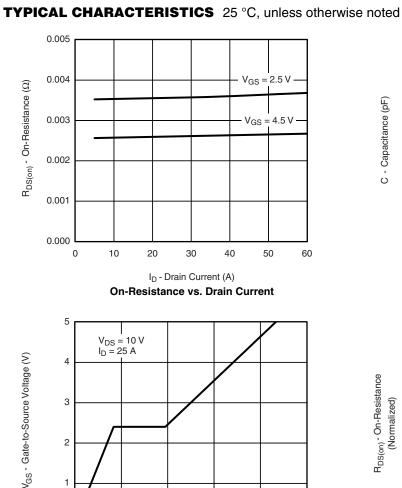
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

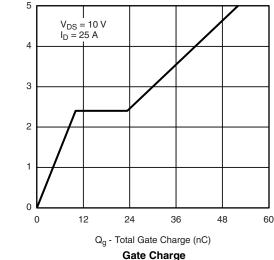


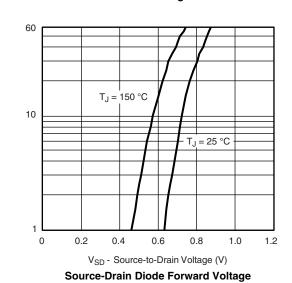


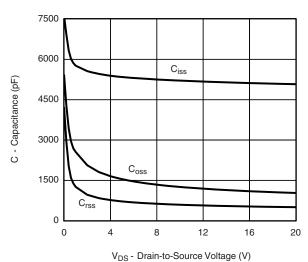




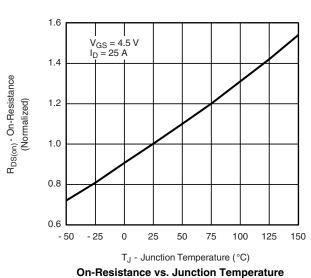


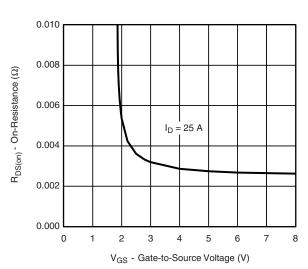






Capacitance





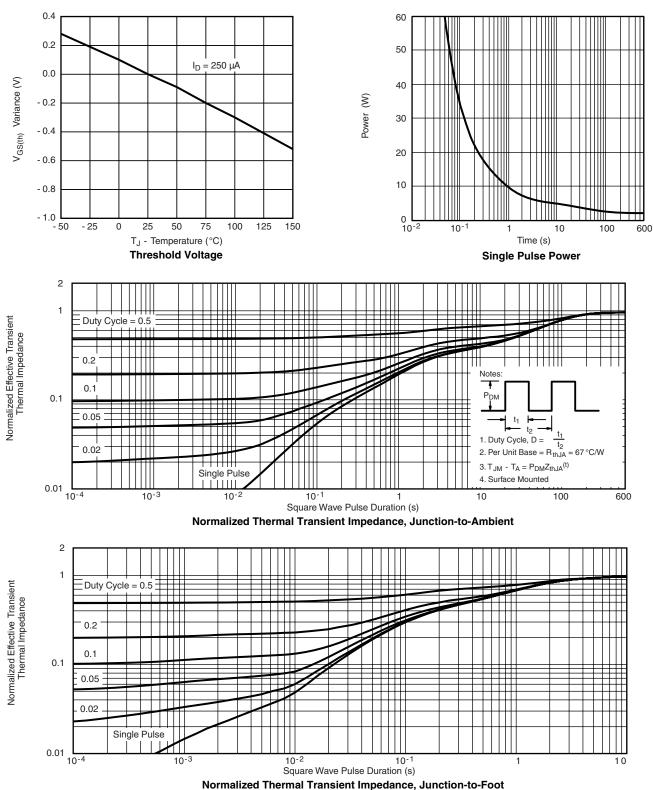
On-Resistance vs. Gate-to-Source Voltage

Source Current (A)

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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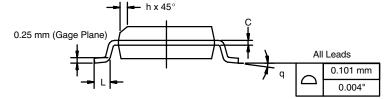




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27 BSC		0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

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DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOT

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